



JAN2N3507AL Information

Heisener.com

Part Number JAN2N3507AL

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 50V 3A TO5 TO-205AA, TO-5-3 Metal Can **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N3507AL Specifications

Manufacturer Part Number	JAN2N3507AL
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AA, TO-5-3 Metal Can
Series	Military, MIL-PRF-19500/349
Transistor Type	NPN
Current - Collector (Ic) (Max)	3A
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 250mA, 2.5A
Current - Collector Cutoff (Max)	-
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 1.5A, 2V
Power - Max	1W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AA, TO-5-3 Metal Can
Supplier Device Package	TO-5
	Report errors?

JAN2N3507AL Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N3507AL Payment Methods



















JAN2N3507AL Shipping Methods













If you have any question about JAN2N3507AL, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com